## NSN 5961-01-212-8010

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View Online at https://aerobasegroup.com/nsn/5961-01-212-8010 **Inclosure Material:** Metal **Overall Length:** 0.210 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.230 inches **End Application:** Satellite communications set, an/wsc- (v) 9 **Internal Configuration:** Field effect **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -25.0 gate non-trigger voltage, dc and -25.0 gate to source voltage **Current Rating Per Characteristic:** 10.00 milliamperes gate current **Power Rating Per Characteristic:** 300.0 milliwatts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Terminal Type And Quantity:** 4 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

Yes - demil/mli

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